



## Glass Passivated High Efficient Rectifiers

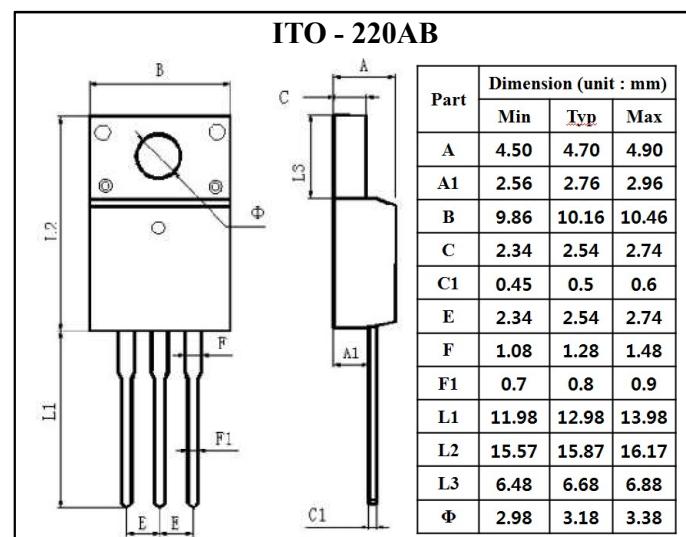
Reverse Voltage 50 to 1000 Volts Forward Current 10.0 Amperes

### Features

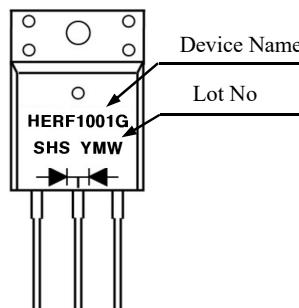
- Low forward voltage drop
- High current capability
- High reliability
- High surge current capability
- For use in low voltage, high frequency inverter, free wheeling, and polarity protection application

### Mechanical Data

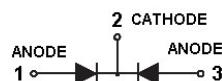
- Case : ITO-220AB Molded plastic
- Epoxy : UL 94V-0 rate flame retardant
- Terminals : Pure tin plated, lead free, solderable per MIL-STD-202, Method 208 guaranteed
- Polarity : As marked
- High temperature soldering guaranteed : 260°C/10 seconds /0.25",(6.35mm) from case
- Mounting torque : 5 in-lbs. max
- Weight : 2.24 grams



### Marking



### Equivalent Circuit



### Maximum Ratings & Electrical Characteristics

Ratings at 25°C ambient temperature unless otherwise specified

Single phase half wave 60 Hz, resistive or inductive load

For capacitive load, derate current by 20%

Parameter	Symbol	HERF 1001G	HERF 1002G	HERF 1003G	HERF 1004G	HERF 1005G	HERF 1006G	HERF 1007G	HERF 1008G	Unit	Remark		
Maximum Repetitive Peak Reverse Voltage	V <sub>RRM</sub>	50	100	200	300	400	600	800	1000	V			
Maximum RMS Voltage	V <sub>RMS</sub>	35	70	140	210	280	420	560	700	V			
Maximum DC Blocking Voltage	V <sub>DC</sub>	50	100	200	300	400	600	800	1000	V			
Maximum Average Forward Rectified Current	I <sub>(AV)</sub>	10.0								A			
Peak Forward Surge Current, 8.3ms Single Half Sine-wave Superimposed on Rated Load (JEDEC method)	I <sub>FSM</sub>	125								A			
Maximum Instantaneous Forward Voltage at 5.0A	V <sub>F</sub>	1.0			1.3	1.7				V			
Maximum DC Reverse Current at Rated DC Blocking Voltage	I <sub>R</sub>	10.0							uA	T <sub>a</sub> =25°C			
		400								T <sub>a</sub> =125°C			
Maximum Reverse Recovery Time	t <sub>rr</sub>	50				80				ns	Note 1		
Typical Junction Capacitance	C <sub>J</sub>	60				40				pF	Note 2		
Typical Thermal Resistance	R <sub>th(j-c)</sub>	3.0							°C/W		Note 3		
Operation Junction Temperature Range	T <sub>J</sub>	-55 to +150							°C				
Storage Temperature Range	T <sub>STG</sub>	-55 to +150							°C				

Note 1. Reverse Recovery Time Test Conditions : I<sub>F</sub>=0.5A, I<sub>R</sub>=1.0A, I<sub>RR</sub>=0.25A

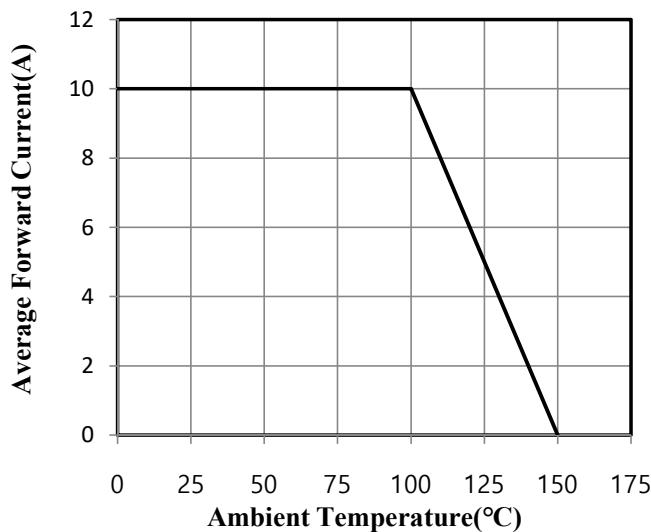
Note 2. Measured at 1MHz and Applied Reverse Voltage of 4.0Volts D.C.

Note 3. Mounted on Heatsink Size of 2 in × 3 in × 0.25 in Al-Plate

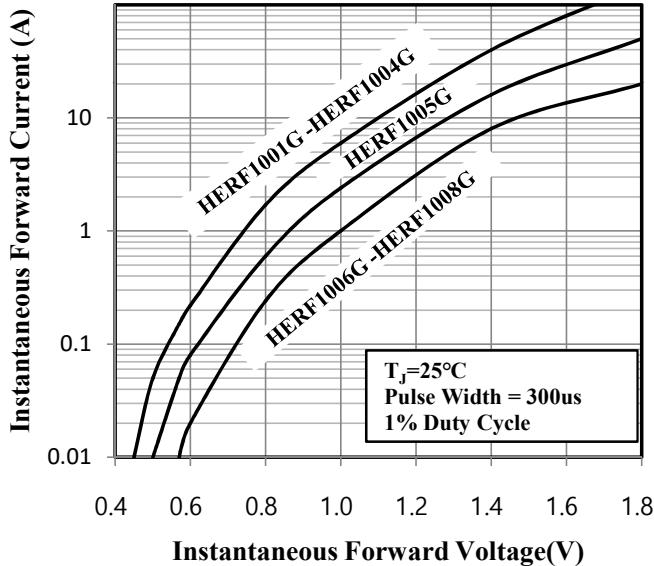


Ratings and Characteristics Curves (Ta=25°C unless otherwise noted)

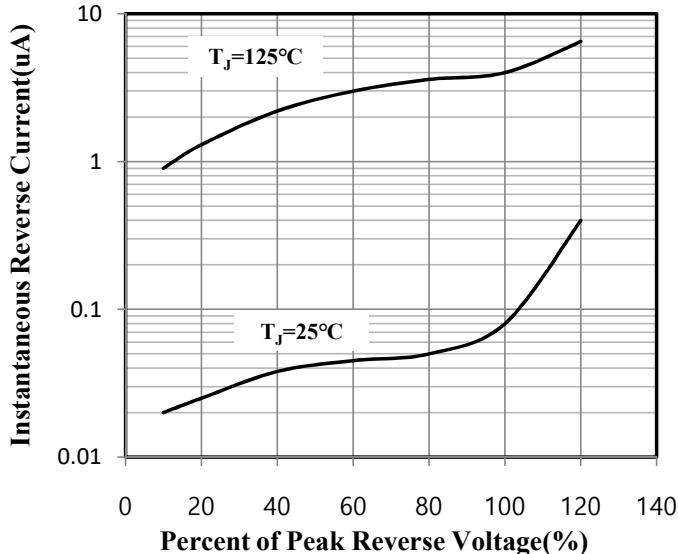
**Fig.1 Forward Current Derating Curve**



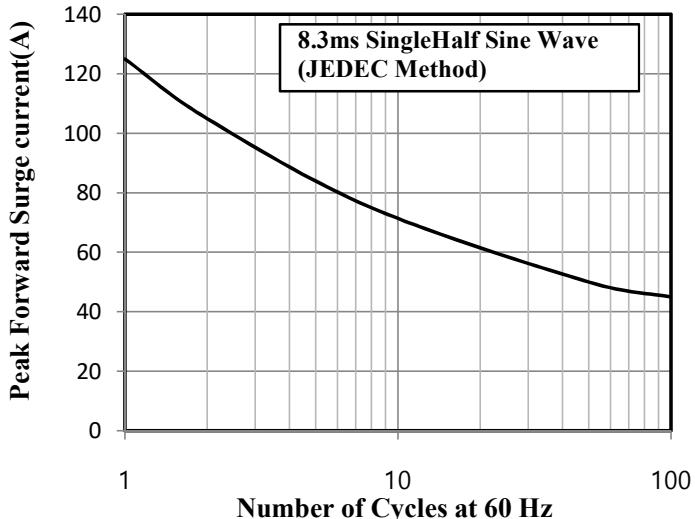
**Fig.3 Typical Instantaneous Forward Characteristics**



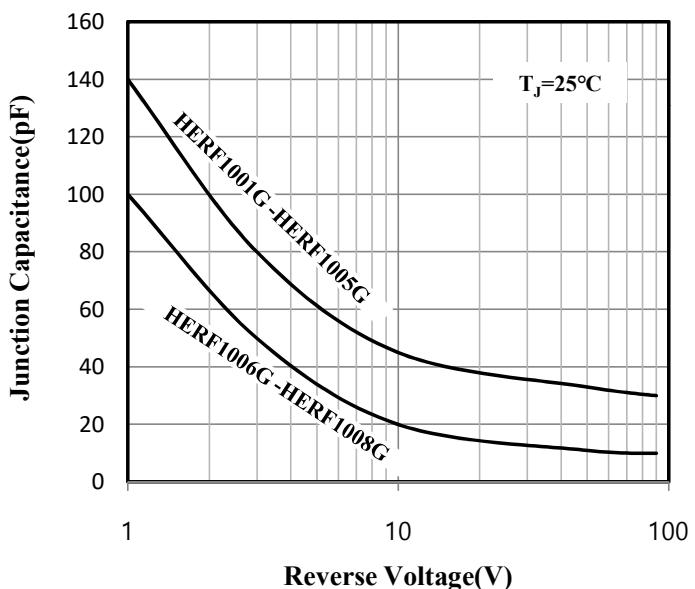
**Fig.5 Typical Reverse Characteristics**



**Fig.2 Maximum Non-Repetitive Peak Forward Surge Current**



**Fig.4 Typical Junction Capacitance**



**Fig. 6 Reverse Recovery Time Characteristic and Test Circuit Diagram**

